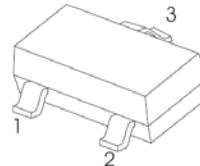


## General Description

These devices are well suited for low voltage and battery powered applications where low in-line power loss is needed in a very small outline surface mount package.

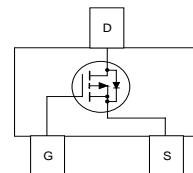
SOT - 23



1. GATE
2. SOURCE
3. DRAIN

## Features

- $-1.3\text{ A}, -30\text{V}$     $R_{DS(ON)} = 180\text{ m}\Omega @ V_{GS} = -10\text{V}$
- $-1.1\text{ A}, -30\text{V}$     $R_{DS(ON)} = 300\text{ m}\Omega @ V_{GS} = -4.5\text{V}$
- High performance trench technology for extremely low  $R_{DS(ON)}$ .
- High power version of industry Standard SOT-23 package. Identical pin-out to SOT-23 with 30% higher power handling capability.



## Applications

- Notebook computer power management

## Absolute Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{DSS}$	Drain-Source Voltage	-30	V
$V_{GSS}$	Gate-Source Voltage	$\pm 25$	V
$I_D$	Drain Current – Continuous (Note 1a)	-1.3	A
	– Pulsed	-10	
$P_D$	Power Dissipation for Single Operation (Note 1a)	0.5	W
	(Note 1b)	0.46	
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$
<b>Thermal Characteristics</b>			
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 1a)	250	$^\circ\text{C}/\text{W}$
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case (Note 1)	75	

**Electrical Characteristics**  $T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
<b>Off Characteristics</b>						
$\text{BV}_{\text{DSS}}$	Drain–Source Breakdown Voltage	$V_{\text{GS}} = 0 \text{ V}$ , $I_D = -250 \mu\text{A}$	-30			V
$\frac{\Delta \text{BV}_{\text{DSS}}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250 \mu\text{A}$ , Referenced to $25^\circ\text{C}$		-17		$\text{mV}/^\circ\text{C}$
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{\text{DS}} = -24 \text{ V}$ , $V_{\text{GS}} = 0 \text{ V}$			-1	$\mu\text{A}$
$I_{\text{GSS}}$	Gate–Body Leakage	$V_{\text{GS}} = \pm 25 \text{ V}$ , $V_{\text{DS}} = 0 \text{ V}$			$\pm 100$	nA
<b>On Characteristics (Note 2)</b>						
$V_{\text{GS(th)}}$	Gate Threshold Voltage	$V_{\text{DS}} = V_{\text{GS}}$ , $I_D = -250 \mu\text{A}$	-0.8	-2.0	-2.5	V
$\frac{\Delta V_{\text{GS(th)}}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \mu\text{A}$ , Referenced to $25^\circ\text{C}$		4		$\text{mV}/^\circ\text{C}$
$R_{\text{DS(on)}}$	Static Drain–Source On–Resistance	$V_{\text{GS}} = -10 \text{ V}$ , $I_D = -1.3 \text{ A}$ $V_{\text{GS}} = -4.5 \text{ V}$ , $I_D = -1.1 \text{ A}$		150 250	180 300	$\text{m}\Omega$
$g_{\text{FS}}$	Forward Transconductance	$V_{\text{DS}} = -5 \text{ V}$ , $I_D = -0.9 \text{ A}$		2.0		S
<b>Dynamic Characteristics</b>						
$C_{\text{iss}}$	Input Capacitance	$V_{\text{DS}} = -15 \text{ V}$ , $V_{\text{GS}} = 0 \text{ V}$ , $f = 1.0 \text{ MHz}$		150		pF
$C_{\text{oss}}$	Output Capacitance			40		pF
$C_{\text{rss}}$	Reverse Transfer Capacitance			20		pF
<b>Switching Characteristics (Note 2)</b>						
$t_{\text{d(on)}}$	Turn–On Delay Time	$V_{\text{DD}} = -10 \text{ V}$ , $I_D = -1 \text{ A}$ , $V_{\text{GS}} = -10 \text{ V}$ , $R_{\text{GEN}} = 6 \Omega$		4	8	ns
$t_r$	Turn–On Rise Time			15	28	ns
$t_{\text{d(off)}}$	Turn–Off Delay Time			10	18	ns
$t_f$	Turn–Off Fall Time			1	2	ns
$Q_g$	Total Gate Charge	$V_{\text{DS}} = -10 \text{ V}$ , $I_D = -0.9 \text{ A}$ , $V_{\text{GS}} = -4.5 \text{ V}$		1.4	1.9	nC
$Q_{\text{gs}}$	Gate–Source Charge			0.5		nC
$Q_{\text{gd}}$	Gate–Drain Charge			0.5		nC
<b>Drain–Source Diode Characteristics and Maximum Ratings</b>						
$I_S$	Maximum Continuous Drain–Source Diode Forward Current				-0.42	A
$V_{\text{SD}}$	Drain–Source Diode Forward Voltage	$V_{\text{GS}} = 0 \text{ V}$ , $I_S = -0.42 \text{ A}$ (Note 2)		-0.8	-1.2	V
$t_{\text{rr}}$	Diode Reverse Recovery Time	$I_F = -3.9 \text{ A}$ , $dI_F/dt = 100 \text{ A}/\mu\text{s}$		17		ns
$Q_{\text{rr}}$	Diode Reverse Recovery Charge			7		nC

**Notes:**

1.  $R_{\thetaJA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins  $R_{\thetaJC}$  is guaranteed by design while  $R_{\thetaJA}$  is determined by the user's board design.

(a)  $R_{\thetaJA} = 250^\circ\text{C}/\text{W}$  when mounted on a 0.02 in<sup>2</sup> pad of 2oz. copper.

(b)  $R_{\thetaJA} = 270^\circ\text{C}/\text{W}$  when mounted on a 0.001 in<sup>2</sup> pad of 2oz. copper.

2. Pulse Test: Pulse Width < 300μs, Duty Cycle < 2.0%

## Typical Characteristics

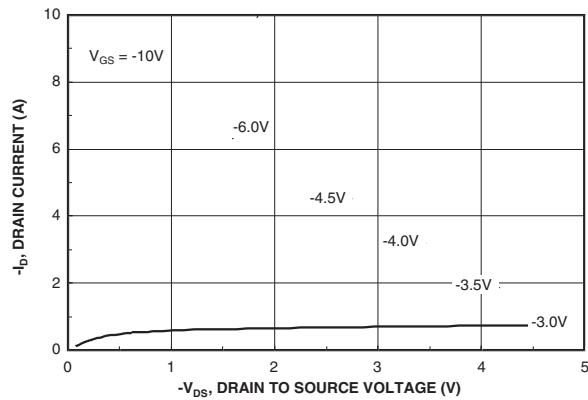


Figure 1. On-Region Characteristics.

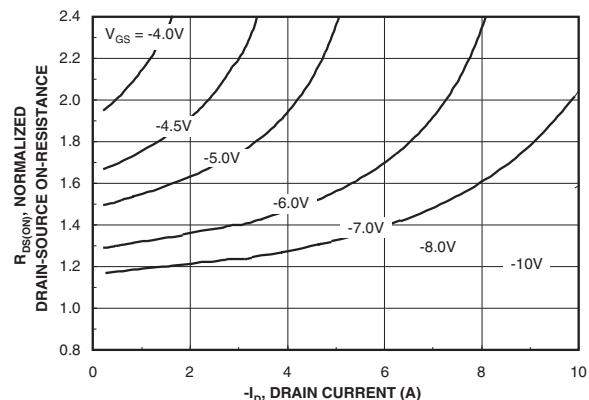


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

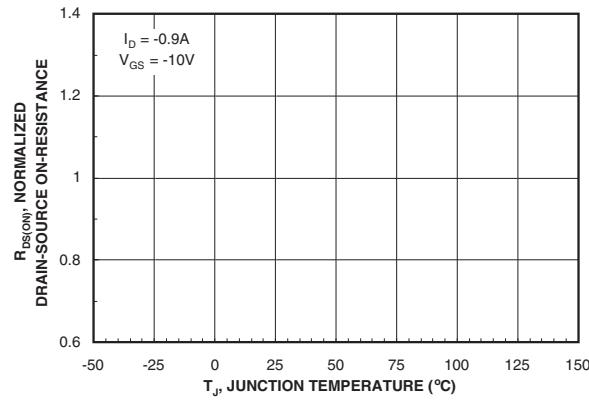


Figure 3. On-Resistance Variation with Temperature.

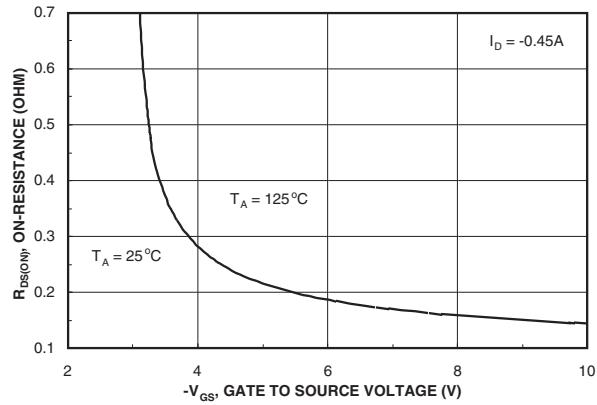


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

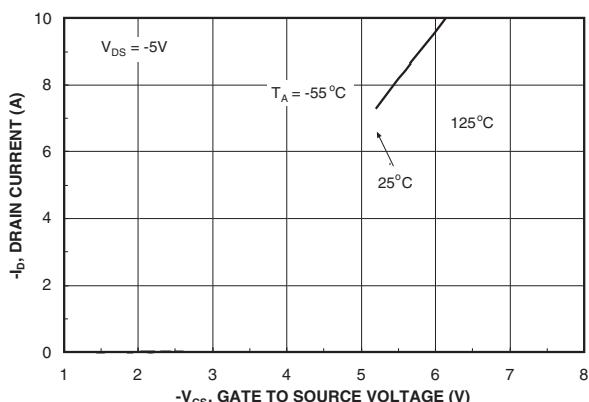


Figure 5. Transfer Characteristics.

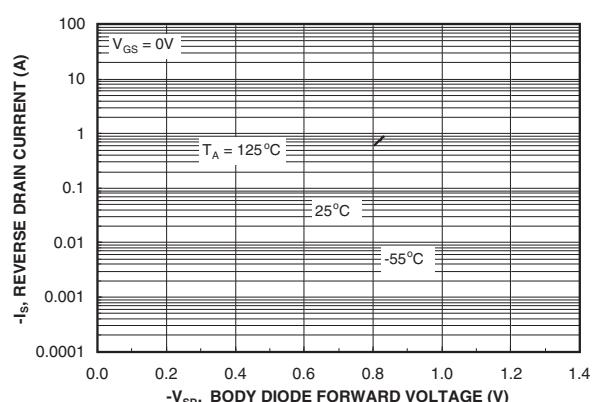
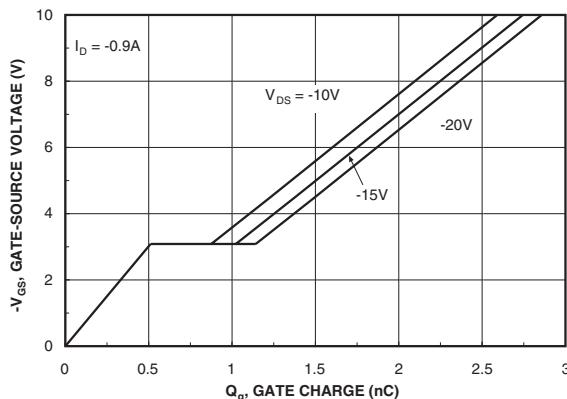
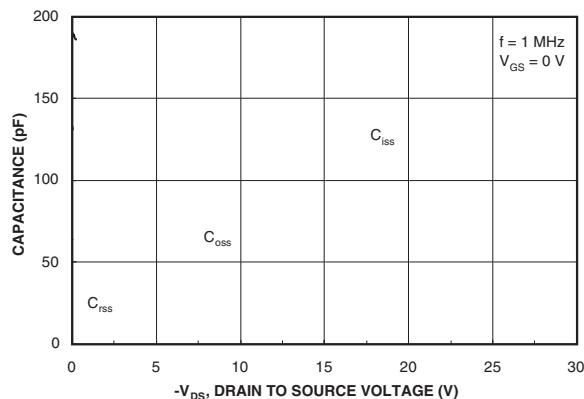


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

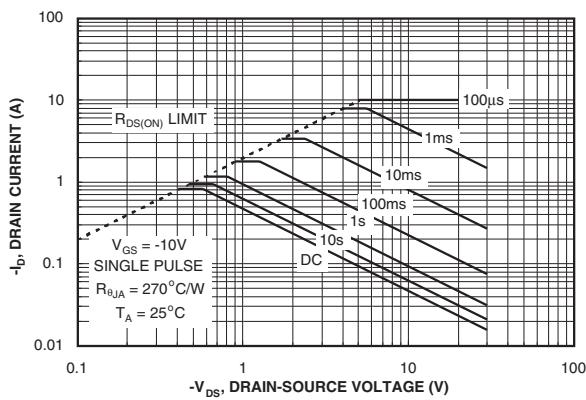
## Typical Characteristics



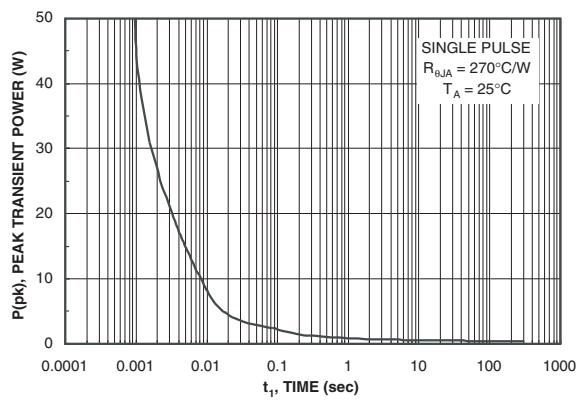
**Figure 7. Gate Charge Characteristics.**



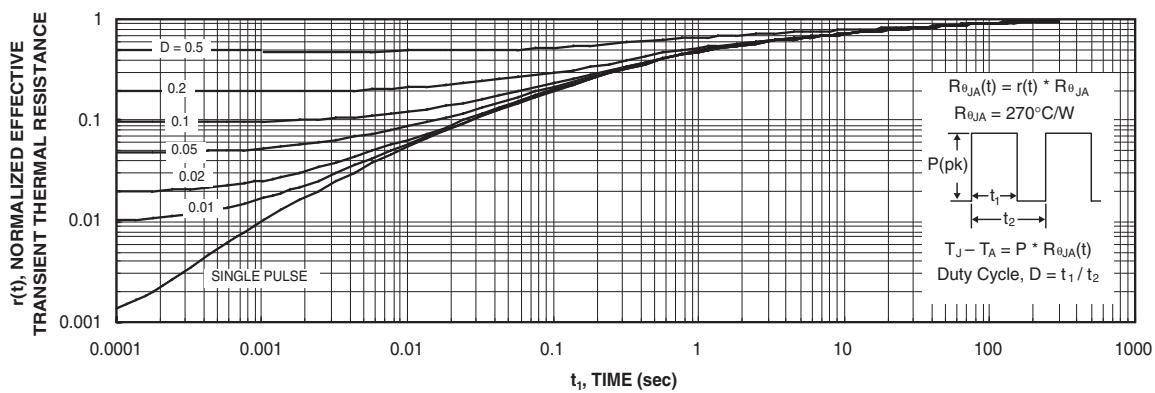
**Figure 8. Capacitance Characteristics.**



**Figure 9. Maximum Safe Operating Area.**

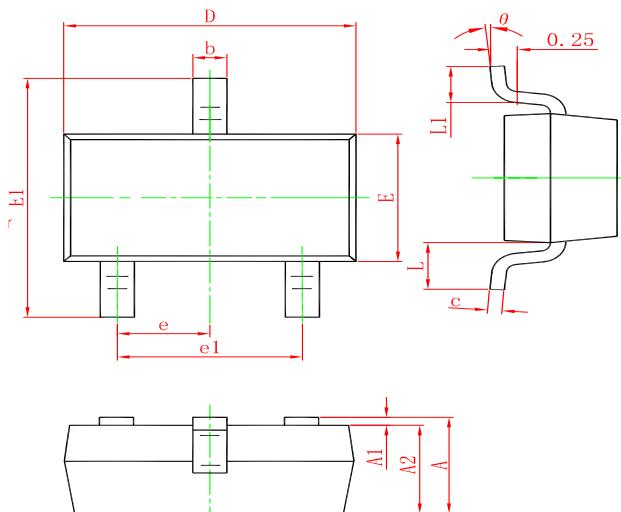


**Figure 10. Single Pulse Maximum Power Dissipation.**

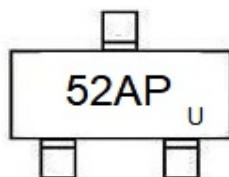


**Figure 11. Transient Thermal Response Curve.**

Thermal characterization performed using the conditions described in Note 1c.  
Transient thermal response will change depending on the circuit board design.

**SOT-23 PACKAGE OUTLINE DIMENSIONS**

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

**Marking****Ordering information**

Order code	Package	Baseqty	Deliverymode
FDN352AP	SOT-23	3000	Tape and reel